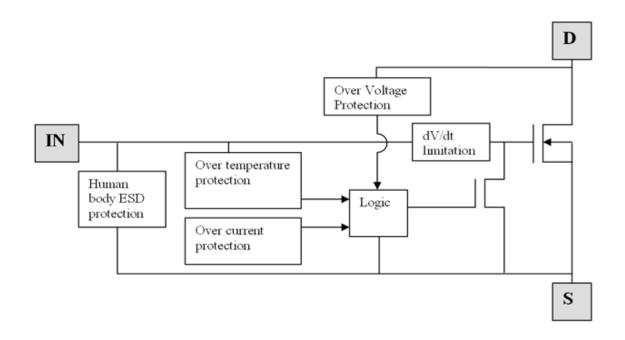


#### **Functional Block Diagram**



# Absolute Maximum Ratings (@T<sub>A</sub>= +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Continuous Drain-Source Voltage	V <sub>DS</sub>	60	V
Drain-Source Voltage for Short Circuit Protection	V <sub>DS(SC)</sub>	24	V
Continuous Input Voltage	V <sub>IN</sub>	-0.5 to +6	V
Continuous Input Current @-0.2V $\leq$ V <sub>IN</sub> $\leq$ 6V Continuous Input Current @V <sub>IN</sub> $<$ -0.2V or V <sub>IN</sub> $>$ 6V	I <sub>IN</sub>	No Limit   I <sub>IN</sub>   ≤ 2	mA
Pulsed Drain Current @V <sub>IN</sub> = 3.3V	I <sub>DM</sub>	5	А
Pulsed Drain Current @V <sub>IN</sub> = 5V	I <sub>DM</sub>	6	Α
Continuous Source Current (Body Diode) (Note 6)	Is	2.5	Α
Pulsed Source Current (Body Diode)	I <sub>SM</sub>	10	Α
Unclamped Single Pulse Inductive Energy, T <sub>J</sub> = +25°C, I <sub>D</sub> = 0.5A, V <sub>DD</sub> = 24V	E <sub>AS</sub>	120	mJ
Electrostatic Discharge (Human Body Model)	V <sub>HBM</sub>	4,000	V
Charged Device Model	V <sub>CDM</sub>	1,000	V

### **Recommended Operating Conditions**

The ZXMS6005N8Q is optimized to use with  $\mu C$  operating from 3.3V and 5V supplies.

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	V <sub>IN</sub>	0	5.5	V
Ambient Temperature Range	T <sub>A</sub>	-40	+125	°C
High Level Input Voltage for MOSFET to be On	VIH	3	5.5	V
Low Level Input Voltage for MOSFET to be Off	V <sub>IL</sub>	0	0.7	V
Peripheral Supply Voltage (Voltage to Which Load is Referred)	V <sub>P</sub>	0	24	V

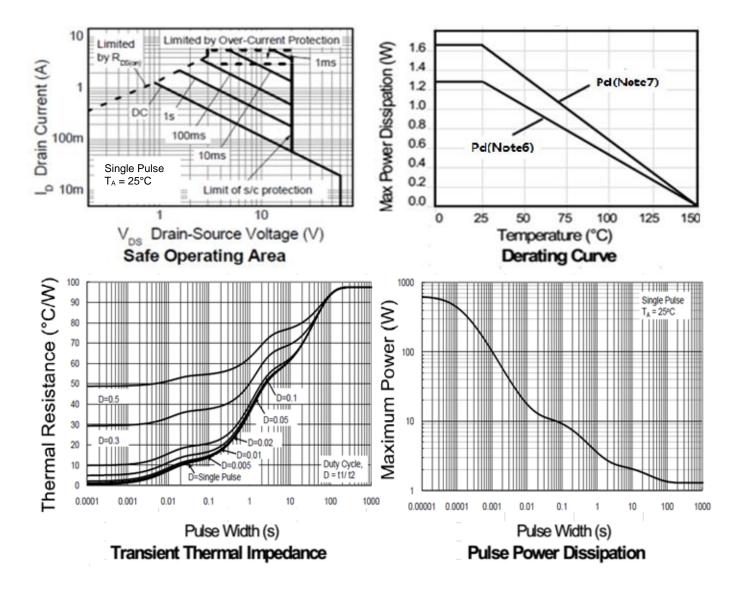


# Thermal Resistance (@T<sub>A</sub>= +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T <sub>A</sub> = +25°C (Note 6) Linear Derating Factor	P <sub>D</sub>	1.28 10	W mW/°C
Power Dissipation at T <sub>A</sub> = +25°C (Note 7) Linear Derating Factor	P <sub>D</sub>	1.65 12.4	W mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	98	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>0JA</sub>	76	°C/W
Thermal Resistance, Junction to Case (Note 8)	ReJC	12	°C/W
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.
- 8. Thermal resistance between junction and the mounting surfaces of drain and source pins.





#### Electrical Characteristics (@T<sub>A</sub>= +25°C, unless otherwise stated.)

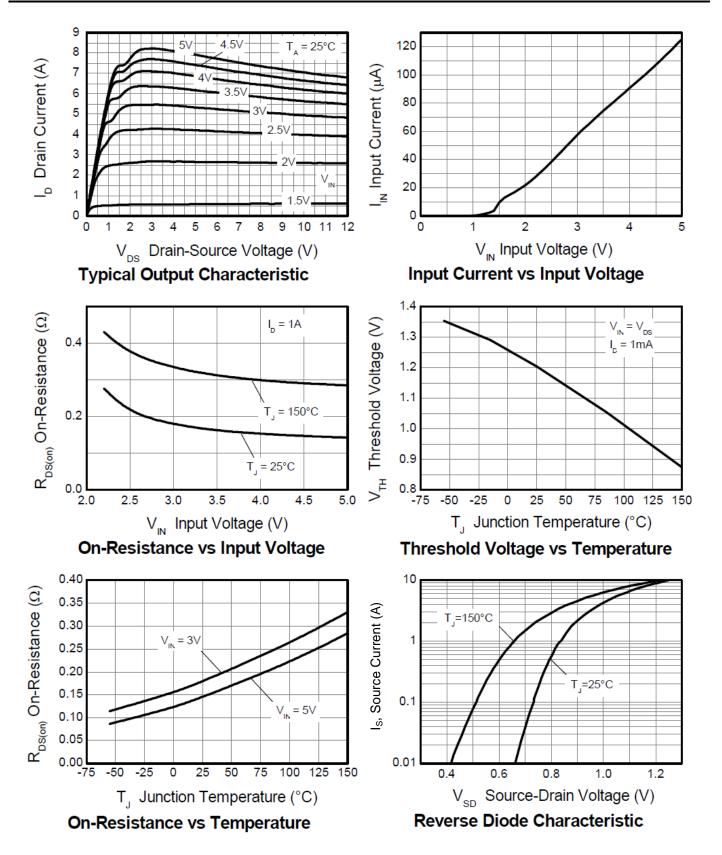
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Static Characteristics							
Drain-Source Clamp Voltage	V <sub>DS(AZ)</sub>	60	65	70	V	$I_D = 10 \text{mA}$	
Off-State Drain Current		_	_	1		$V_{DS} = 12V, V_{IN} = 0V$	
	I <sub>DSS</sub>		_	2	μΑ	$V_{DS} = 36V, V_{IN} = 0V$	
Input Threshold Voltage	V <sub>IN(TH)</sub>	0.7	1	1.5	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$	
Innut Current	I <sub>IN</sub>		60	100	μΑ	V <sub>IN</sub> = 3V	
Input Current		_	120	200		$V_{IN} = 5V$	
Input Current While Overtemperature Active	_	_	_	300	μΑ	V <sub>IN</sub> = 5V	
Static Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	_	170	250	mΩ	$V_{IN} = 3V, I_D = 1.0A$	
Static Drain-Source On-State Resistance		_	150	200	mu	$V_{IN} = 5V, I_D = 1.0A$	
Continuous Prais Current (Note 6)		1.4	_			V <sub>IN</sub> = 3V, T <sub>A</sub> = +25°C	
Continuous Drain Current (Note 6)	I <sub>D</sub>	1.6	_		Α	$V_{IN} = 5V, T_A = +25^{\circ}C$	
Continuous Drain Current (Note 7)		1.9	_			$V_{IN} = 3V, T_A = +25^{\circ}C$	
Continuous Drain Current (Note 7)		2.0	_	_		$V_{IN} = 5V, T_A = +25^{\circ}C$	
Current Limit (Note 9)	I <sub>D(LIM)</sub>	2.2	5	_	А	$V_{IN} = 3V$	
Current Limit (Note 9)		3.3	7	_		$V_{IN} = 5V$	
Dynamic Characteristics							
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5	_			
Rise Time	t <sub>R</sub>	_	14	_	0	10)/ 1 0 5 1 1/ 5 1/	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	34		μs	$V_{DD} = 12V$ , $I_D = 0.5A$ , $V_{GS} = 5V$	
Fall Time	t <sub>F</sub>	_	19	_			
Overtemperature Protection							
Thermal Overload Trip Temperature (Note 10)	$T_{JT}$	+150	+175	_	°C	_	
Thermal Hysteresis (Note 10)	$\Delta T_{JT}$	_	+10		°C	_	

Notes:

The drain current is restricted only when the device is in saturation (see graph "Typical Output Characteristic"). This allows the device to be used in the fully on state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.
 Overtemperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods.

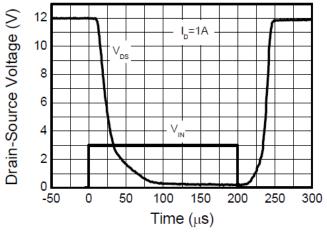


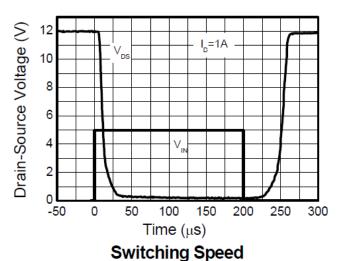
# **Typical Characteristics**



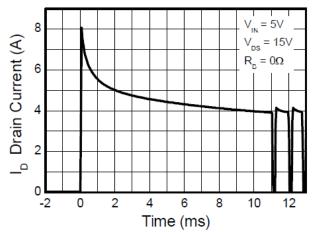


# **Typical Characteristics** (Cont.)





**Switching Speed** 



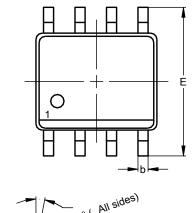
**Typical Short Circuit Protection** 

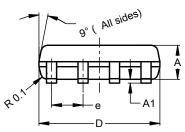


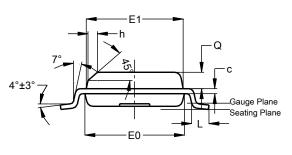
### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8





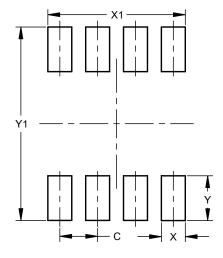


SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
q	0.30	0.50	0.40		
C	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
Ф			1.27		
h	-		0.35		
Г	0.62	0.82	0.72		
Ø	0.60	0.70	0.65		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50



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